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in the following listed application(s) or patent(s) for which the issue fee has been paid.

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7,859,606 B2	10/576,177	12/28/2010	04/19/2006	7224	0553-0494

Respectfully Submitted,

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Higaki et al.

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SEMICONDUCTOR DEVICE (54)

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ABSTRACT (57)

It is an object of the present invention to connect a wiring, an electrode, or the like formed with two incompatible films (an ITO film and an aluminum film) without increasing the crosssectional area of the wiring and to achieve lower power consumption even when the screen size becomes larger. The present invention provides a two-layer structure including an upper layer and a lower layer having a larger width than the upper layer. A first conductive layer is formed with Ti or Mo, and a second conductive layer is formed with aluminum (pure aluminum) having low electric resistance over the first conductive layer. A part of the lower layer projected from the end section of the upper layer is bonded with ITO.

28 Claims, 14 Drawing Sheets

